

74HC175D

1. Functional Description

- Quad D-Type Flip-Flop with Clear

2. General

The 74HC175D is a high speed CMOS D-TYPE FLIP FLOP fabricated with silicon gate C²MOS technology.

It achieves the high speed operation similar to equivalent LSTTL while maintaining the CMOS low power dissipation.

Information signals applied to D inputs are transferred to the Q and \bar{Q} outputs on the positive going edge of the clock pulse.

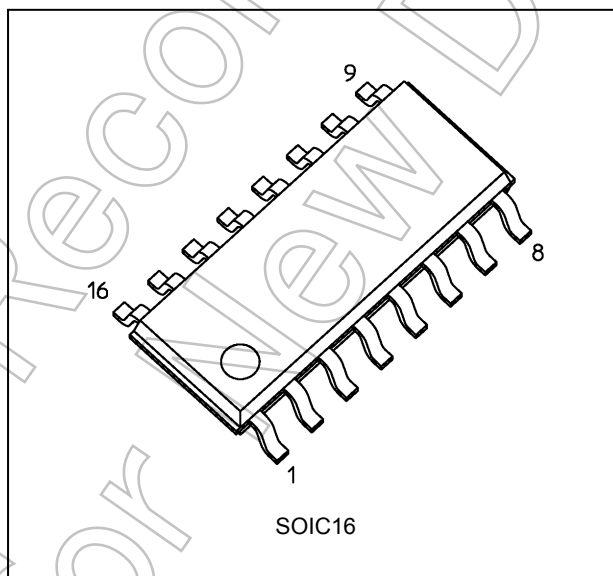
When the $\overline{\text{CLR}}$ input is held low, the Q outputs are at the low logic level and the \bar{Q} outputs are at the high logic level independent of the other inputs.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

3. Features

- (1) High speed: $f_{\text{MAX}} = 63 \text{ MHz (typ.)}$ at $V_{\text{CC}} = 5 \text{ V}$
- (2) Low power dissipation: $I_{\text{CC}} = 4.0 \mu\text{A (max)}$ at $T_{\text{a}} = 25 \text{ }^\circ\text{C}$
- (3) Balanced propagation delays: $t_{\text{PLH}} \approx t_{\text{PHL}}$
- (4) Wide operating voltage range: $V_{\text{CC(opr)}} = 2.0 \text{ V to } 6.0 \text{ V}$

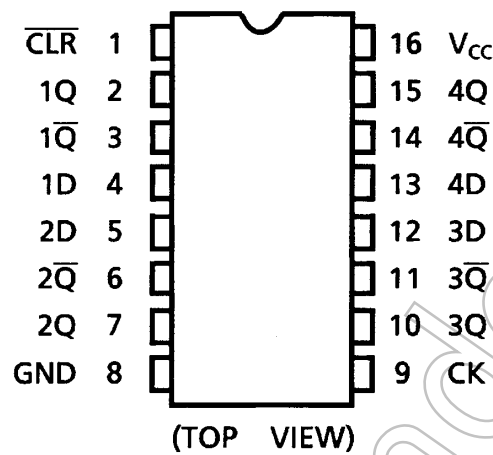
4. Packaging



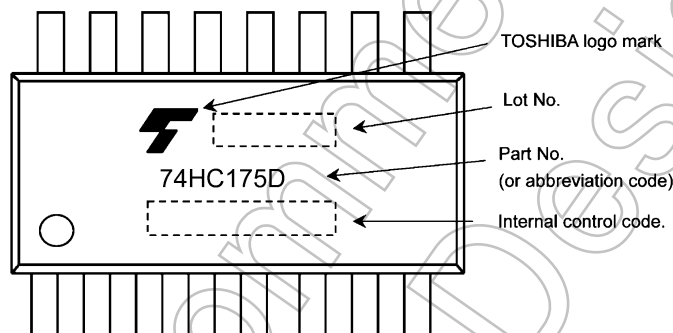
Start of commercial production

2016-05

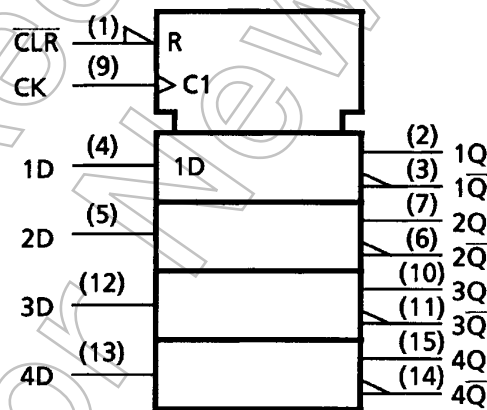
5. Pin Assignment



6. Marking



7. IEC Logic Symbol

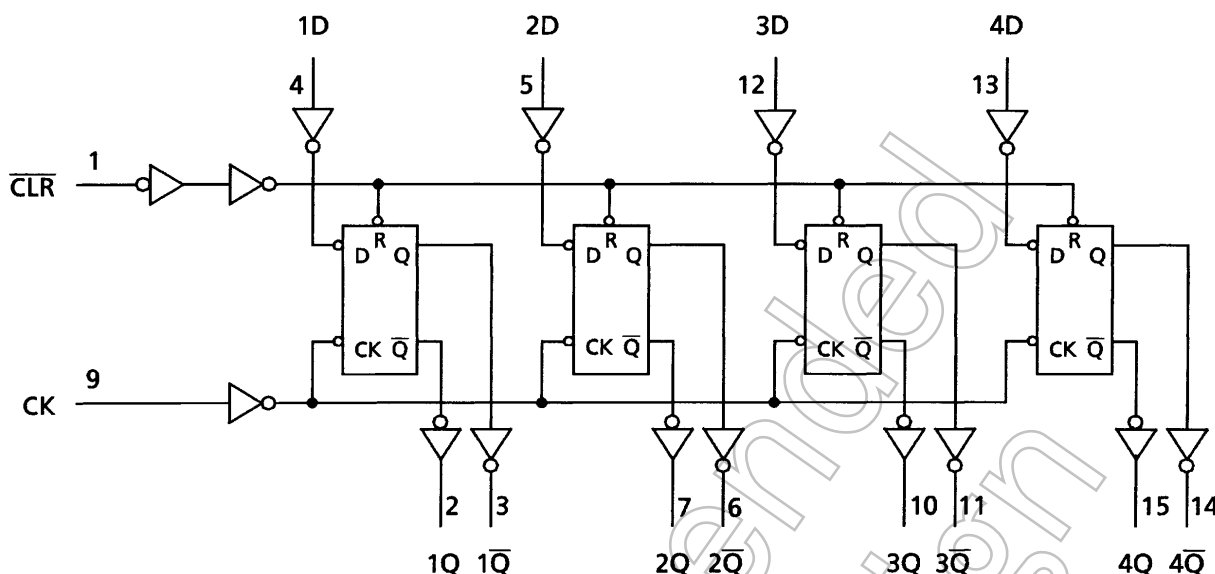


8. Truth Table

Inputs			Outputs		Function
CLR	D	CK	Q	Q̄	
L	X	X	L	H	Clear
H	L	↑	L	H	—
H	H	↑	H	L	—
H	X	↓	Q _n	Q̄ _n	No Change

X: Don't care

9. System Diagram



10. Absolute Maximum Ratings (Note)

Characteristics	Symbol	Note	Rating	Unit
Supply voltage	V_{CC}		-0.5 to 7.0	V
Input voltage	V_{IN}		-0.5 to $V_{CC} + 0.5$	V
Output voltage	V_{OUT}		-0.5 to $V_{CC} + 0.5$	V
Input diode current	I_{IK}		± 20	mA
Output diode current	I_{OK}		± 20	mA
Output current	I_{OUT}		± 25	mA
V_{CC} /ground current	I_{CC}		± 50	mA
Power dissipation	P_D	(Note 1)	500	mW
Storage temperature	T_{stg}		-65 to 150	$^{\circ}C$

Note: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook (“Handling Precautions”/“Derating Concept and Methods”) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 1: P_D derates linearly with -8 mW/ $^{\circ}C$ above 85 $^{\circ}C$

11. Operating Ranges (Note)

Characteristics	Symbol	Test Condition	Rating	Unit
Supply voltage	V_{CC}	—	2.0 to 6.0	V
Input voltage	V_{IN}	—	0 to V_{CC}	V
Output voltage	V_{OUT}	—	0 to V_{CC}	V
Operating temperature	T_{opr}	—	-40 to 125	$^{\circ}C$
Input rise and fall times	t_r, t_f	—	0 to 50	μs

Note: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either V_{CC} or GND.

12. Electrical Characteristics

12.1. DC Characteristics (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Typ.	Max	Unit	
High-level input voltage	V_{IH}	—		2.0	1.50	—	—	V	
				4.5	3.15	—	—		
				6.0	4.20	—	—		
Low-level input voltage	V_{IL}	—		2.0	—	—	0.50	V	
				4.5	—	—	1.35		
				6.0	—	—	1.80		
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\text{ }\mu\text{A}$	2.0	1.9	2.0	—	V	
				4.5	4.4	4.5	—		
				6.0	5.9	6.0	—		
			$I_{OH} = -4\text{ mA}$	4.5	4.18	4.31	—		
				$I_{OH} = -5.2\text{ mA}$	6.0	5.68	5.80		—
					6.0	—	—		—
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\text{ }\mu\text{A}$	2.0	—	0.0	0.1	V	
				4.5	—	0.0	0.1		
				6.0	—	0.0	0.1		
			$I_{OL} = 4\text{ mA}$	4.5	—	0.17	0.26		
				$I_{OL} = 5.2\text{ mA}$	6.0	—	0.18		0.26
					6.0	—	—		—
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND		6.0	—	—	± 0.1	μA	
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND		6.0	—	—	4.0	μA	

12.2. DC Characteristics (Unless otherwise specified, $T_a = -40$ to $85\text{ }^\circ\text{C}$)

Characteristics	Symbol	Test Condition		V_{CC} (V)	Min	Max	Unit	
High-level input voltage	V_{IH}	—		2.0	1.50	—	V	
				4.5	3.15	—		
				6.0	4.20	—		
Low-level input voltage	V_{IL}	—		2.0	—	0.50	V	
				4.5	—	1.35		
				6.0	—	1.80		
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20\text{ }\mu\text{A}$	2.0	1.9	—	V	
				4.5	4.4	—		
				6.0	5.9	—		
			$I_{OH} = -4\text{ mA}$	4.5	4.13	—		
				$I_{OH} = -5.2\text{ mA}$	6.0	5.63		—
					6.0	—		—
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20\text{ }\mu\text{A}$	2.0	—	0.1	V	
				4.5	—	0.1		
				6.0	—	0.1		
			$I_{OL} = 4\text{ mA}$	4.5	—	0.33		
				$I_{OL} = 5.2\text{ mA}$	6.0	—		0.33
					6.0	—		—
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND		6.0	—	± 1.0	μA	
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND		6.0	—	40.0	μA	

12.3. DC Characteristics (Unless otherwise specified, $T_a = -40$ to 125 °C)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit				
High-level input voltage	V_{IH}	—	2.0	1.50	—	V				
			4.5	3.15	—					
			6.0	4.20	—					
Low-level input voltage	V_{IL}	—	2.0	—	0.50	V				
			4.5	—	1.35					
			6.0	—	1.80					
High-level output voltage	V_{OH}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OH} = -20 \mu A$	2.0	1.9	—	V			
				4.5	4.4	—				
				6.0	5.9	—				
			$I_{OH} = -4$ mA	4.5	3.7	—				
				6.0	$I_{OH} = -5.2$ mA	5.2		—		
						—		—		
Low-level output voltage	V_{OL}	$V_{IN} = V_{IH}$ or V_{IL}	$I_{OL} = 20 \mu A$	2.0	—	0.1	V			
				4.5	—	0.1				
				6.0	—	0.1				
			4.5	$I_{OL} = 4$ mA	0.4	—		0.4		
					6.0	$I_{OL} = 5.2$ mA		—	—	0.4
								—	—	—
Input leakage current	I_{IN}	$V_{IN} = V_{CC}$ or GND	6.0	—	± 1.0	μA				
Quiescent supply current	I_{CC}	$V_{IN} = V_{CC}$ or GND	6.0	—	160.0	μA				

Not Recommended for New Design

12.4. Timing Requirements (Unless otherwise specified, $T_a = 25\text{ }^\circ\text{C}$, Input: $t_r = t_f = 6\text{ ns}$)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Typ.	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	—	2.0	—	75	ns
			4.5	—	15	
			6.0	—	13	
Minimum pulse width (CLR)	$t_{w(L)}$	—	2.0	—	75	ns
			4.5	—	15	
			6.0	—	13	
Minimum setup time	t_s	—	2.0	—	75	ns
			4.5	—	15	
			6.0	—	13	
Minimum hold time	t_h	—	2.0	—	0	ns
			4.5	—	0	
			6.0	—	0	
Minimum removal time	t_{rem}	—	2.0	—	75	ns
			4.5	—	15	
			6.0	—	13	
Clock frequency	f	—	2.0	—	6	MHz
			4.5	—	31	
			6.0	—	36	

12.5. Timing Requirements (Unless otherwise specified, $T_a = -40\text{ to }85\text{ }^\circ\text{C}$, Input: $t_r = t_f = 6\text{ ns}$)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	—	2.0	95	ns
			4.5	19	
			6.0	16	
Minimum pulse width (CLR)	$t_{w(L)}$	—	2.0	95	ns
			4.5	19	
			6.0	16	
Minimum setup time	t_s	—	2.0	95	ns
			4.5	19	
			6.0	16	
Minimum hold time	t_h	—	2.0	0	ns
			4.5	0	
			6.0	0	
Minimum removal time	t_{rem}	—	2.0	95	ns
			4.5	19	
			6.0	16	
Clock frequency	f	—	2.0	5	MHz
			4.5	25	
			6.0	29	

12.6. Timing Requirements
 (Unless otherwise specified, $T_a = -40$ to 125 °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Limit	Unit
Minimum pulse width (CK)	$t_{w(L)}, t_{w(H)}$	—	2.0	110	ns
			4.5	22	
			6.0	19	
Minimum pulse width (CLR)	$t_{w(L)}$	—	2.0	110	ns
			4.5	22	
			6.0	19	
Minimum setup time	t_s	—	2.0	110	ns
			4.5	22	
			6.0	19	
Minimum hold time	t_h	—	2.0	0	ns
			4.5	0	
			6.0	0	
Minimum removal time	t_{rem}	—	2.0	110	ns
			4.5	22	
			6.0	19	
Clock frequency	f	—	2.0	4	MHz
			4.5	20	
			6.0	24	

12.7. AC Characteristics
 (Unless otherwise specified, $C_L = 15$ pF, $V_{CC} = 5$ V, $T_a = 25$ °C, Input: $t_r = t_f = 6$ ns)

Characteristics	Symbol	Test Condition	Min	Typ.	Max	Unit
Output transition time	t_{TLH}, t_{THL}	—	—	4	8	ns
Propagation delay time (CK-Q, Q)	t_{PLH}, t_{PHL}	—	—	16	24	ns
Propagation delay time (CLR-Q, Q)	t_{PLH}, t_{PHL}	—	—	13	21	ns
Maximum clock frequency	f_{MAX}	—	36	63	—	MHz

12.8. AC Characteristics (Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = 25 \text{ }^\circ\text{C}$, Input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Note	Test Condition	V_{CC} (V)	Min	Typ.	Max	Unit
Output transition time	t_{TLH}, t_{THL}		—	2.0	—	30	75	ns
				4.5	—	8	15	
				6.0	—	7	13	
Propagation delay time (CK-Q, \bar{Q})	t_{PLH}, t_{PHL}		—	2.0	—	70	140	ns
				4.5	—	19	28	
				6.0	—	16	24	
Propagation delay time (CLR-Q, \bar{Q})	t_{PLH}, t_{PHL}		—	2.0	—	50	125	ns
				4.5	—	16	25	
				6.0	—	12	22	
Maximum clock frequency	f_{MAX}		—	2.0	6	14	—	MHz
				4.5	31	53	—	
				6.0	36	63	—	
Input capacitance	C_{IN}		—	—	3	—	pF	
Power dissipation capacitance	C_{PD}	(Note 1)	—	—	5	—	pF	

Note 1: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation.

$$I_{CC(opr)} = C_{PD} \times V_{CC} \times f_{IN} + I_{CC}/4 \text{ (per F/F)}$$

And the total C_{PD} when n pcs of latch operate can be gained by the following equation.

$$C_{PD} \text{ (total)} = 32 + 21 \times n$$

12.9. AC Characteristics (Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = -40 \text{ to } 85 \text{ }^\circ\text{C}$, Input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit
Output transition time	t_{TLH}, t_{THL}	—	2.0	—	95	ns
			4.5	—	19	
			6.0	—	16	
Propagation delay time (CK-Q, \bar{Q})	t_{PLH}, t_{PHL}	—	2.0	—	175	ns
			4.5	—	35	
			6.0	—	30	
Propagation delay time (CLR-Q, \bar{Q})	t_{PLH}, t_{PHL}	—	2.0	—	160	ns
			4.5	—	32	
			6.0	—	27	
Maximum clock frequency	f_{MAX}	—	2.0	5	—	MHz
			4.5	25	—	
			6.0	29	—	

12.10. AC Characteristics

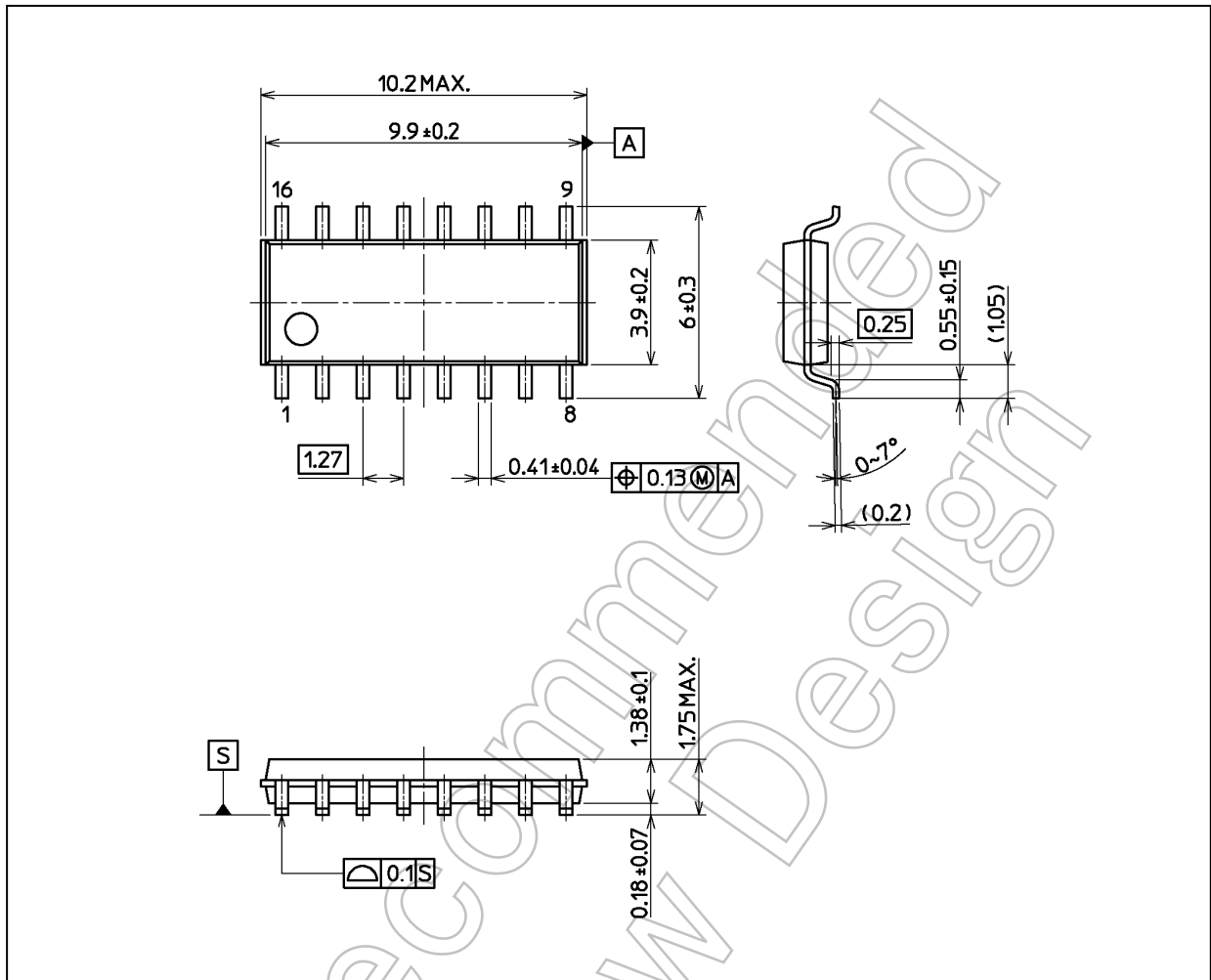
(Unless otherwise specified, $C_L = 50 \text{ pF}$, $T_a = -40 \text{ to } 125 \text{ }^\circ\text{C}$, Input: $t_r = t_f = 6 \text{ ns}$)

Characteristics	Symbol	Test Condition	V_{CC} (V)	Min	Max	Unit
Output transition time	t_{TLH}, t_{THL}	—	2.0	—	110	ns
			4.5	—	22	
			6.0	—	19	
Propagation delay time (CK-Q, \bar{Q})	t_{PLH}, t_{PHL}	—	2.0	—	210	ns
			4.5	—	42	
			6.0	—	36	
Propagation delay time (CLR-Q, \bar{Q})	t_{PLH}, t_{PHL}	—	2.0	—	190	ns
			4.5	—	38	
			6.0	—	32	
Maximum clock frequency	f_{MAX}	—	2.0	4	—	MHz
			4.5	20	—	
			6.0	24	—	

Not Recommended for New Designs

Package Dimensions

Unit: mm



Weight: 0.15 g (typ.)

Package Name(s)
Nickname: SOIC16

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